

Photocoupler



K5610 • K5611

These Photocouplers consist of a Gallium Arsenide Infrared Emitting Diode and a Silicon NPN Phototransistor in a 6-pin package.

FEATURES

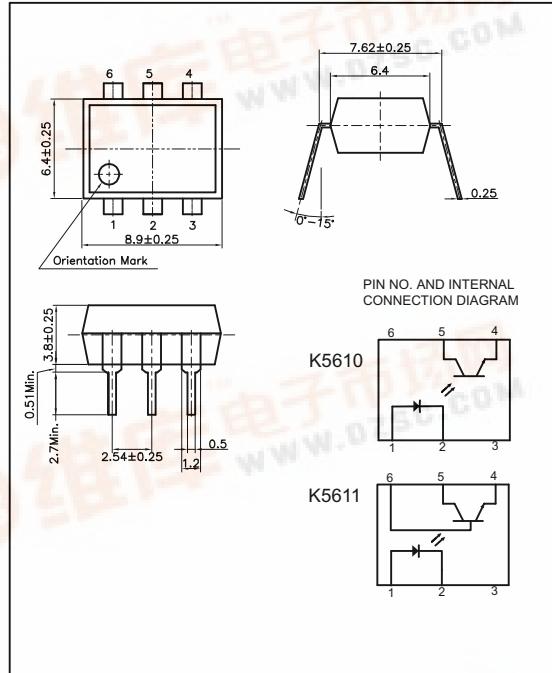
- TTL Compatible Output
- Collector-Emitter Voltage : Min.70V
- Current Transfer Ratio : Typ.50% (at $I_F=5\text{mA}$, $V_{CE}=5\text{V}$)
- Electrical Isolation Voltage : AC5000Vrms
- UL Recognized File No. E107486

APPLICATIONS

- Interface between two circuits of different potential
- Vending Machine, Copiers
- Measuring Instrument
- Home Appliances

DIMENSION

(Unit : mm)



MAXIMUM RATINGS

(Ta=25 °C)

	Parameter	Symbol	Rating	Unit
Input	Forward Current	I _F	50	mA
	Reverse Voltage	V _R	5	V
	Peak Forward Current ^{*1}	I _{FP}	1	A
	Power Dissipation	P _D	70	mW
Output	Collector-Emitter Breakdown Voltage	BV _{CEO}	70	V
	Emitter-Collector Breakdown Voltage	BV _{ECO}	7	V
	Collector-Base Breakdown Voltage**	BV _{CBO}	80	V
	Collector Current	I _C	50	mA
	Collector Power Dissipation	P _C	150	mW
Input to Output Isolation Voltage ^{*2}		V _{iso}	AC5000	V _{rms}
Storage Temperature		T _{stg}	-55~+125	
Operating Temperature		T _{opr}	-30~+100	
Lead Soldering Temperature ^{*3}		T _{sol}	260	
Total Power Dissipation		P _{tot}	200	mW

^{**} Except for K5610^{*1}. Input current with $100\mu\text{s}$ pulse width, 1% duty cycle^{*2}. Measured at RH=40~60% for 1min^{*3}. 1/16 inch form case for 10sec

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ELECTRO-OPTICAL CHARACTERISTICS

(Ta=25 °C, unless otherwise noted)

Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit.
Input	Forward Voltage	V _F	I _F =10mA	-	1.15	1.30	V
	Reverse Current	I _R	V _R =5V	-	-	10	μA
	Capacitance	C _T	V=0, f=1MHz	-	30	-	pF
Output	Collector-Emitter Breakdown Voltage	BV _{C EO}	I _C =1mA	70	-	-	V
	Emitter-Collector Breakdown Voltage	BV _{E CO}	I _E =0.1mA	7	-	-	V
	Collector-Base Breakdown Voltage **	BV _{C BO}	I _C =0.1mA	80	-	-	V
	Collector Dark Current	I _{C EO}	I _F =0, V _{C E} =24V	-	-	100	nA
	Capacitance	C _{C E}	V _{C E} =0, f=1MHz	-	10	-	pF
Coupled	Current Transfer Ratio *4	CTR	I _F =5mA, V _{C E} =5V	50	-	600	%
	Collector-Emitter Saturation Voltage	V _{C E(SAT)}	I _F =5mA, I _C =1mA	-	-	0.3	V
	Input-Output Capacitance	C _{I O}	V=0, f=1MHz	-	1	-	pF
	Input-Output Isolation Resistance	R _{I O}	RH=40~60%, V=500V	-	10 ¹¹	-	
	Rise Time	tr	V _{C E} =10V, R _L =100Ω	-	3	-	μs
	Fall Time	tf	I _C =2mA	-	3	-	μs

** Except for K5610

*4. CTR=(I_C/I_F) X 100 (%)

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